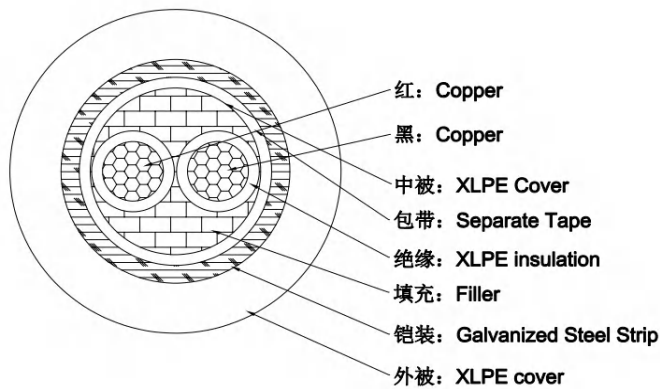


CONSTRUCTION ITEM / 结构项目		LD-WDZEE23 2x4mm ²		
CONDUCTOR 导体	CONSTRUCTION 构造规格	AWG	4mm ² (56/0.285±0.008)TS	
	MATERIAL/ 导体材质	-----	Tinned annealed stranded copper	
	DIAM OF STRANDS 绞合外径	mm	2.46±0.1	
INSULATION 绝缘	MATERIAL 材质	-----	Halogen free crosslinked polyolefin	
	OVER DIAMETER 芯线外径	mm	4.2±0.15mm	
	AVG THICK OF INSU/平均绝缘厚度	mm	0.8	
	MIN THICK OF INSU/最小绝缘厚度	mm	0.62	
	COLOR/ 颜色	-----	RED、BLACK	
INNER-ASSEMBLE 内集合	DIRECTION/ 绞向	-----	RIGHT SIDE	
	OVER DIAMETER/ 绞合外径	mm	8.4	
OUTSIDE TAPE WRAP 外部包装	INSULATION LAYER/ 隔离层	-----	Non-woven fabric	
	OVETLAP RATE/ 重叠率	-----	Gap wrapping	
Inner Sheath 内护套	MATERIAL/ 材质	-----	Halogen free crosslinked polyolefin	
	MIN THICK OF INSU/最小绝缘厚度		0.44	
OUTSIDE SHIELD 外部遮蔽	MATERIAL/ 材质	-----	Galvanized Steel Strip	
	CONSTRUCTION/ 构造	-----	2 Layers 0.2mm	
	COVERAGE/ 遮蔽率	%	100%(Gap wrapping)	
JACKET/ 外被	MATERIAL/ 材质	-----	Halogen free crosslinked polyolefin	
	DIAMETER/ 线径	mm	13.6±0.5	
	AVERAGE THICKNESS/ 平均厚度	mm	0.8	
	SURFACE/ 外观	-----	Smooth	
	COLOR/ 颜色	-----	BLACK	
	MARKING COLOR/ 印字颜色	-----	WHITE	
MARKING/ 印字	LD-WDZEE23 1800V 2x6mm ² CEEIA B218.2-2012 LEADER TECHNOLOGY SHENZHEN CO.,LIMITED			
CHARACTERISTIC 性能	CONDUCTOR RESISTANCE 导体电阻(20°C)	-----	Max.5.09 ohms/km	
	INSULATION RESISTANCE 绝缘电阻	Ω·cm	Min. 10 ¹² (20°C)	
	SPARK TEST 火花测试	KV/mi	6.5/5 (AC) No breakdown	
	RATE DTEMPERATUR 额定温度	°C	-40~90	
	VOLTAGE RATING 额定电压	V	DC 1800V	
	老化前	ELONGATION 伸长率	%	125
		TENS STRENGTH 抗张强度	N/mm ²	8.0
FLAME TEST 耐燃测试	-----	Single flame retardant test		





CONSTRUCTION ITEM / 结构项目		LD-WDZEE23 2x6mm ²		
CONDUCTOR 导体	CONSTRUCTION 构造规格	AWG	6mm ² (84/0.285±0.008)TS	
	MATERIAL/导体材质	----	Tinned Copper	
	DIAM OF STRANDS 绞合外径	mm	3.02 ±1	
INSULATION 绝缘	MATERIAL 材质	----	Halogen Free crosslinked polyolefin	
	OVER DIAMETER 芯线外径	mm	4.7±0.2mm	
	AVG THICK OF INSU/平均绝缘厚度	mm	0.8	
	MIN THICK OF INSU/最小绝缘厚度	mm	0.62	
	COLOR/ 颜色	----	RED、BLACK	
INNER-ASSEMBLE 内集合	DIRECTION/ 绞向	----	RIGHT SIDE	
	OVER DIAMETER/绞合外径	mm	9.4	
OUTSIDE TAPE WRAP 外部包装	INSULATION LAYER/隔离层	----	Non-woven fabric	
	OVETLAP RATE/重叠率	----	Gap wrapping	
Inner Sheath 内护套	MATERIAL/材质	----	Halogen Free crosslinked polyolefin	
	MIN THICK OF INSU/最小绝缘厚度		0.44	
OUTSIDE SHIELD 外部遮蔽	MATERIAL/材质	----	Galvanized Steel Strip	
	CONSTRUCTION/ 构造	----	2 Layers 0.2mm	
	COVERAGE/ 遮蔽率	%	100%(Gap wrapping)	
JACKET/ 外被	MATERIAL/材质	----	Halogen Free crosslinked polyolefin	
	DIAMETER/线径	mm	15±0.5	
	AVERAGE THICKNESS/平均厚度	mm	1	
	SURFACE/ 外观	----	Smooth	
	COLOR/ 颜色	----	BLACK	
	MARKING C O L O R/ 印字颜色	----	WHITE	
MARKING/ 印字	LD-WDZEE23 1800V 2x6mm ² CEEIA B218.2-2012 LEADER TECHNOLOGY SHENZHEN CO.,LIMITED			
CHARACTERISTIC 性能	CONDUCTORRESISTANCE 导体电阻(20℃)	----	Max.3.39 ohms/km	
	INSULATION RESISTANCE 绝缘电阻率	Ω · cm	Min. 10 ¹² (20℃)	
	SPARK TEST 火花测试	KV/min	6.5/5 (AC) No breakdown	
	RATE DTEMPERATUR 额定温度	℃	-40~90	
	VOLTAGE RATING 额定电压	V	DC 1800V	
	老化前	ELONGATION 伸长率	%	125
		TENS STRENGTH 抗张强度	N/mm ²	8.0
	FLAME TEST耐燃测试	-----	Single flame retardant test	

